



PATENT
Customer No. 22,852
Attorney Docket No. 04329.2308

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)
)
Atsushi MURAKOSHI et al.) Group Art Unit: 2881
)
Application No.: 09/559,345) Examiner: Kiet Tuan Nguyen
)
Filed: April 27, 2000)
)
For: ION GENERATION METHOD)
AND FILAMENT FOR ION)
GENERATION APPARATUS)

Commissioner for Patents
Washington, DC 20231

Sir:

AMENDMENT

RECEIVED
JUN 11 2002
TC 2002-1012-130M

In reply to the Office Action dated March 14, 2002, please amend the application as follows:

IN THE SPECIFICATION:

Please amend the specification as follows:

Please delete the paragraph on page 30, lines 7-11, and replace with the following:

Re is contained in tungsten in the above explanation, but the present invention is not limited to this. Even if any one of the Ce, Nd, Sm, Eu, Gd, Er, Yb, Lu, Sc, Y and La is contained, the same advantage can be obtained.

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